



# PJS6416

## 20V N-Channel Enhancement Mode MOSFET

Voltage

20 V

Current

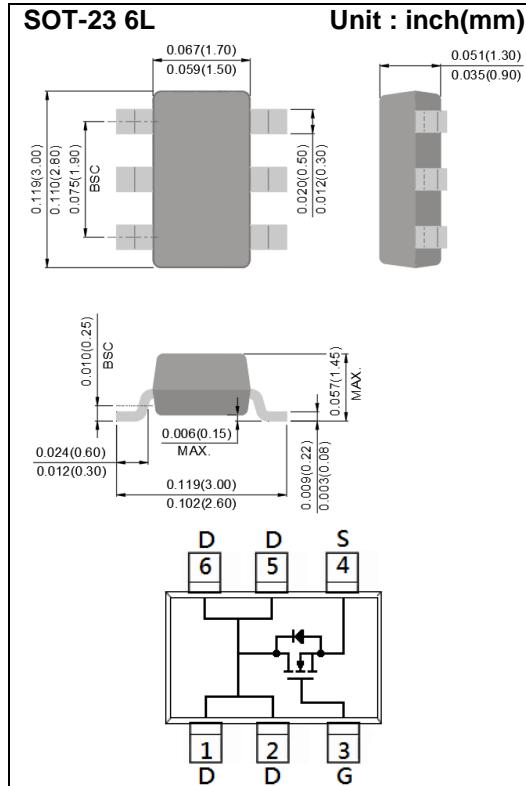
7.4A

### Features

- R<sub>DS(ON)</sub> , V<sub>GS</sub>@4.5V, I<sub>D</sub>@7.4A<27mΩ
- R<sub>DS(ON)</sub> , V<sub>GS</sub>@2.5V, I<sub>D</sub>@4.7A<41mΩ
- R<sub>DS(ON)</sub> , V<sub>GS</sub>@1.8V, I<sub>D</sub>@1.8A<85mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc..
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### Mechanical Data

- Case: SOT-23 6L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0005 ounces, 0.014 grams
- Marking: S16



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V <sub>DS</sub>	20	V
Gate-Source Voltage	V <sub>GS</sub>	+12	V
Continuous Drain Current	I <sub>D</sub>	7.4	A
Pulsed Drain Current	I <sub>DM</sub>	29.6	A
Power Dissipation	T <sub>a</sub> =25°C	2	W
	Derate above 25°C	16	mW/°C
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55~150	°C
Typical Thermal Resistance - Junction to Ambient (Note 3)	R <sub>θJA</sub>	62.5	°C/W



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## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=250\mu\text{A}$	20	-	-	V
Gate Threshold Voltage	$V_{\text{GS(th)}}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$	0.5	0.77	1.2	V
Drain-Source On-State Resistance	$R_{\text{DS(on)}}$	$V_{\text{GS}}=4.5\text{V}, I_{\text{D}}=7.4\text{A}$	-	24	27	$\text{m}\Omega$
		$V_{\text{GS}}=2.5\text{V}, I_{\text{D}}=4.7\text{A}$	-	33	41	
		$V_{\text{GS}}=1.8\text{V}, I_{\text{D}}=1.8\text{A}$	-	62	85	
Zero Gate Voltage Drain Current	$I_{\text{DSS}}$	$V_{\text{DS}}=20\text{V}, V_{\text{GS}}=0\text{V}$	-	0.01	1	$\mu\text{A}$
Gate-Source Leakage Current	$I_{\text{GSS}}$	$V_{\text{GS}}=\pm 12\text{V}, V_{\text{DS}}=0\text{V}$	-	$\pm 10$	$\pm 100$	nA
<b>Dynamic</b>						
Total Gate Charge	$Q_g$	$V_{\text{DS}}=10\text{V}, I_{\text{D}}=7.4\text{A}, V_{\text{GS}}=4.5\text{V}^{(\text{Note 1,2})}$	-	6.8	-	nC
Gate-Source Charge	$Q_{\text{gs}}$		-	1.3	-	
Gate-Drain Charge	$Q_{\text{gd}}$		-	2	-	
Input Capacitance	$C_{\text{iss}}$	$V_{\text{DS}}=10\text{V}, V_{\text{GS}}=0\text{V}, f=1.0\text{MHZ}$	-	513	-	pF
Output Capacitance	$C_{\text{oss}}$		-	74	-	
Reverse Transfer Capacitance	$C_{\text{rss}}$		-	60	-	
<b>Switching</b>						
Turn-On Delay Time	$t_{\text{d(on)}}$	$V_{\text{DD}}=10\text{V}, I_{\text{D}}=7.4\text{A}, V_{\text{GS}}=4.5\text{V}, R_{\text{G}}=6\Omega^{(\text{Note 1,2})}$	-	7	-	ns
Turn-On Rise Time	$t_{\text{r}}$		-	57	-	
Turn-Off Delay Time	$t_{\text{d(off)}}$		-	24	-	
Turn-Off Fall Time	$t_{\text{f}}$		-	14	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_{\text{s}}$	---	-	-	2.0	A
Diode Forward Voltage	$V_{\text{SD}}$	$I_{\text{s}}=1.0\text{A}, V_{\text{GS}}=0\text{V}$	-	0.69	1.2	V

### NOTES :

1. Pulse width  $\leq 300\mu\text{s}$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\text{OJA}}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
4. The maximum current rating is package limited



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## TYPICAL CHARACTERISTIC CURVES

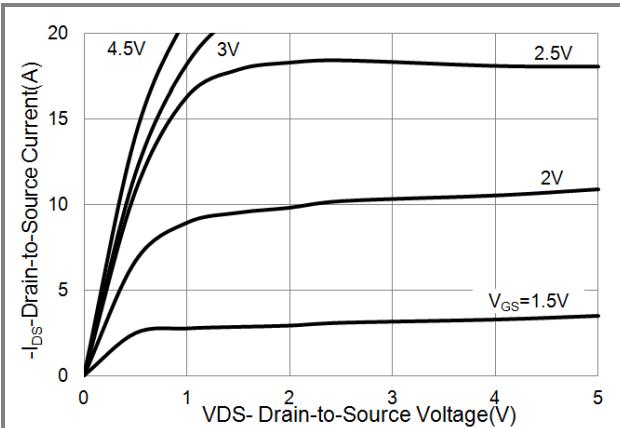


Fig.1 On-Region Characteristics

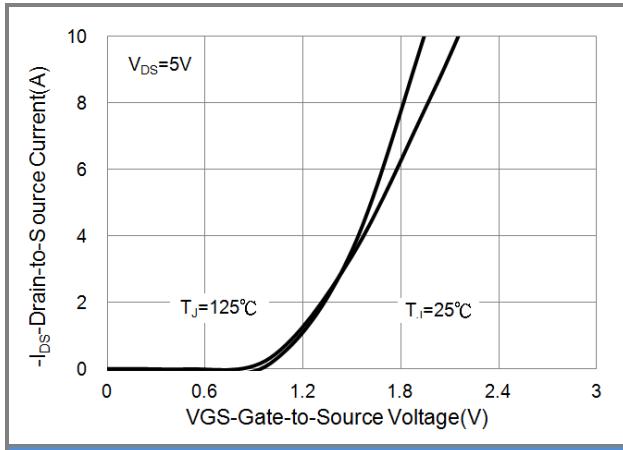


Fig.2 Transfer Characteristics

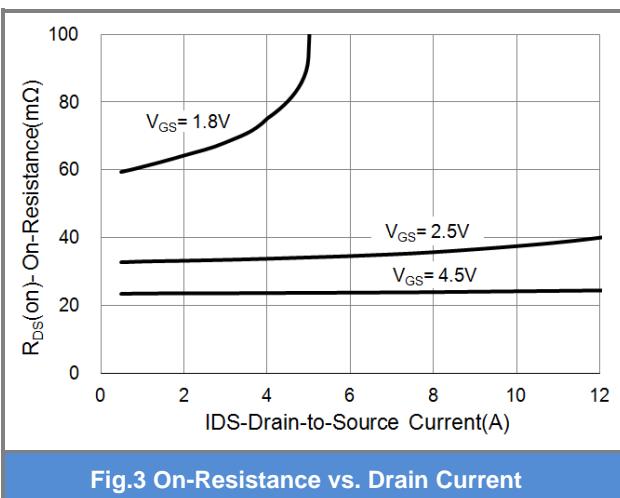


Fig.3 On-Resistance vs. Drain Current

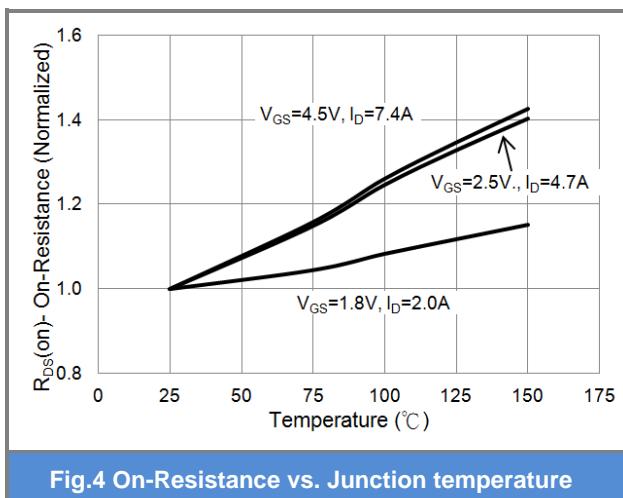


Fig.4 On-Resistance vs. Junction temperature

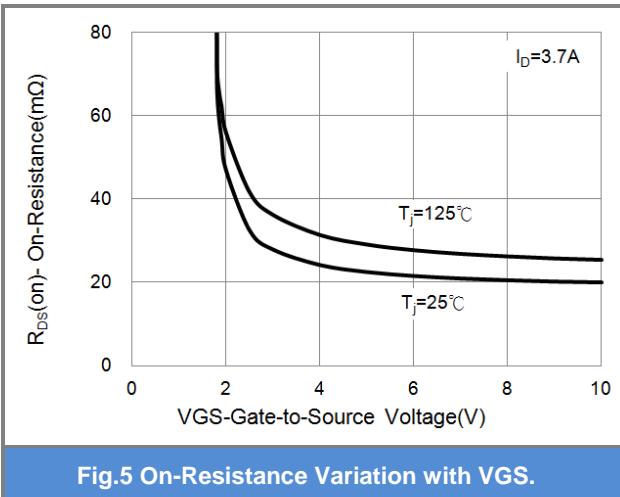


Fig.5 On-Resistance Variation with VGS.

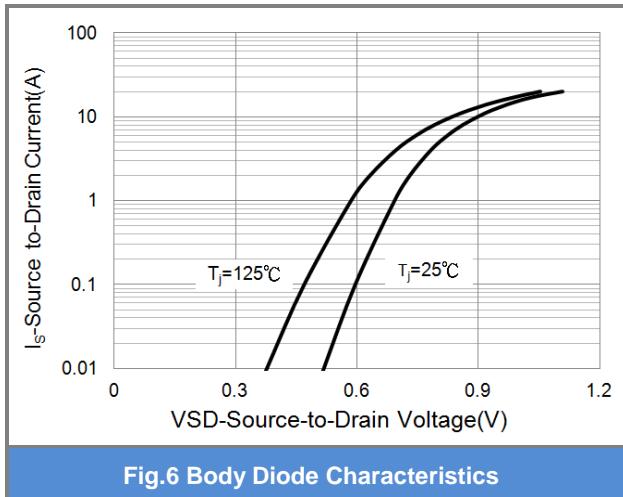


Fig.6 Body Diode Characteristics



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### TYPICAL CHARACTERISTIC CURVES

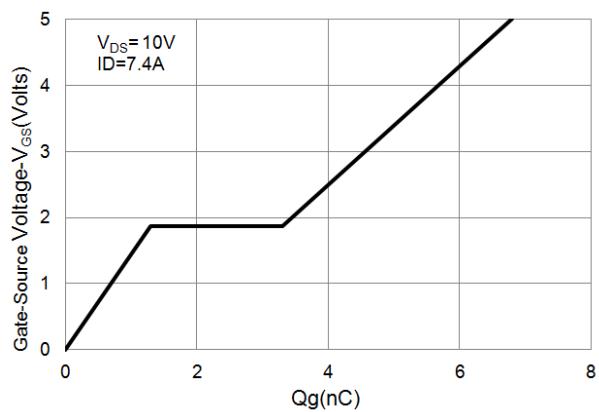


Fig.7 Gate-Charge Characteristics

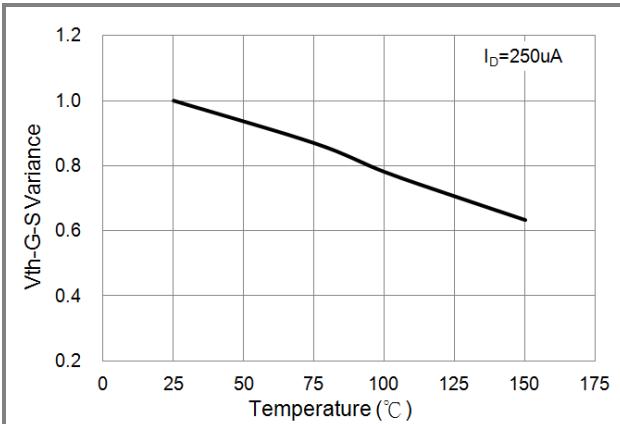


Fig.8 Threshold Voltage Variation with Temperature.

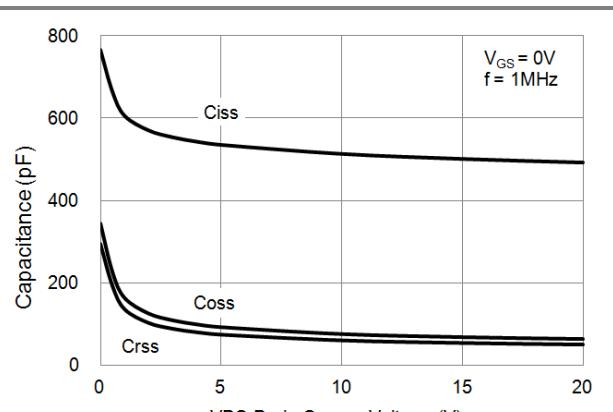


Fig.9 Capacitance vs. Drain-Source Voltage.



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## PART NO. PACKING CODE VERSION

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJS6416_S1_00001	SOT-23 6L	3K pcs / 7" reel	S16	Halogen free RoHS compliant
PJS6416_S2_00001	SOT-23 6L	10K pcs / 13" reel	S16	Halogen free RoHS compliant

## MOUNTING PAD LAYOUT

